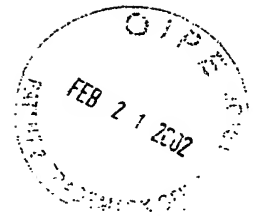


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**AMENDED CLAIM 1 REWRITTEN IN CLEAN FORM  
PURSUANT TO 37 CFR 1.121(c)**

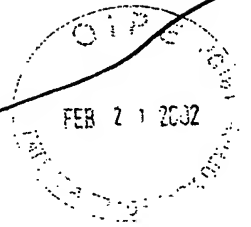
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Please substitute this claim 1 for the pending claim with the same number.

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- Sub B1  
X1
1. (Amended) A semiconductor laser having a laser beam-emitting facet including a laser beam-emitting region, the semiconductor laser comprising a three-dimensional feature portion indicating the location of the light-emitting region formed on the laser beam-emitting facet at a region different from the light emitting region.

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AMENDED CLAIM 2 REWRITTEN IN CLEAN FORM  
PURSUANT TO 37 CFR 1.121(c)

B1  
  
X1  
med.  
  
← Please substitute this claim 2 for the pending claim with the same number. 7

2. (Amended) The semiconductor laser as claimed in claim 1, wherein the three-dimensional feature portion is at least one of a concavity and a convexity formed on the laser beam-emitting facet at a region different from the light-emitting region.

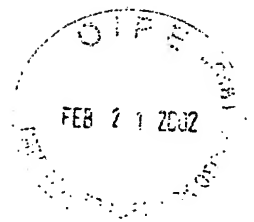
**AMENDED CLAIM 6 REWRITTEN IN CLEAN FORM  
PURSUANT TO 37 CFR 1.121(c)**

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Please substitute this claim 6 for the pending claim with the same number.

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6. (Amended) The semiconductor laser as claimed in claim 3, further comprising a dielectric film provided between the laser beam-emitting facet and the light-shielding film, part of the dielectric film being exposed at the small opening.
-



AMENDED CLAIM 7 REWRITTEN IN CLEAN FORM  
PURSUANT TO 37 CFR 1.121(c)

⌞ Please substitute this claim 7 for the pending claim with the same number. 7

7. (Amended) The semiconductor laser as claimed in claim 4, further comprising a dielectric film provided between the laser beam-emitting facet and the light-shielding film, part of the dielectric film being exposed at the small opening.

72  
Cmpd.

AMENDED CLAIM 8 REWRITTEN IN CLEAN FORM  
PURSUANT TO 37 CFR 1.121(c)

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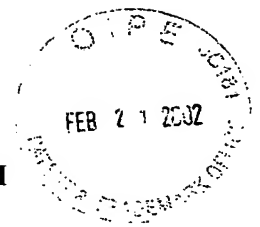
< Please substitute this claim 8 for the pending claim with the same number. 7

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8. (Amended) A method of producing a semiconductor laser having a laser beam-emitting facet including a laser beam-emitting region comprising a step of forming a three-dimensional feature portion at a location on the laser beam-emitting facet to have a prescribed relationship with the light-emitting region.

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Done  
By  
A2  
CMB.



AMENDED CLAIM 11 REWRITTEN IN CLEAN FORM  
PURSUANT TO 37 CFR 1.121(c)

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Please substitute this claim 11 for the pending claim with the same number.

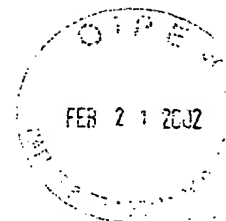
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11. (Amended) The method as claimed in claim 8, further comprising a step of irradiating at least the light-emitting region of the laser beam-emitting facet with a focused ion beam before the step of forming the three-dimensional feature portion.

**AMENDED CLAIM 12 REWRITTEN IN CLEAN FORM  
PURSUANT TO 37 CFR 1.121(c)**

8x  
12 on D.  
Please substitute this claim 12 for the pending claim with the same number.

12. (Amended) The method as claimed in claim 9, further comprising a step of irradiating at least the light-emitting region of the laser beam-emitting facet with a focused ion beam before the step of forming the three-dimensional feature portion.



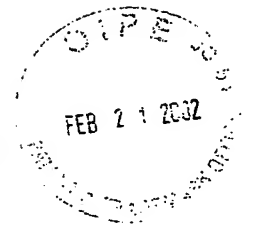
AMENDED CLAIM 13 REWRITTEN IN CLEAN FORM  
PURSUANT TO 37 CFR 1.121(c)

← Please substitute this claim 13 for the pending claim with the same number. →

13. (Amended) The method as ~~claimed~~ in claim 10, further comprising a step of irradiating at least the light-emitting region of the laser beam-emitting facet with a focused ion beam before the step of forming the three-dimensional feature portion.

73  
Cmp.





AMENDED CLAIM 14 REWRITTEN IN CLEAN FORM  
PURSUANT TO 37 CFR 1.121(c)

Please substitute this claim 14 for the pending claim with the same number. 7

14. (Amended) An evanescent optical head for reading/writing of data from/to a recording medium using evanescent light, the evanescent optical head being equipped with a semiconductor laser for emitting the evanescent light that has a laser beam-emitting facet including a light-emitting region and comprises a three-dimensional feature portion formed on laser beam-emitting facet, a light shielding film covering at least the light-emitting region, and a small opening for emitting the evanescent light formed in the light-shielding film at a location to have a prescribed positional relationship with the three-dimensional feature portion.